NSN 5961-01-267-4601

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Inclosure Material:
Metal
Overall Length:
1.573 inches
Overall Height:
0.300 inches
Overall Width:
1.050 inches
End Application:
P-3 orion; aircraft, viking 2-3b
Mounting Facility Quantity:
2
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-3
Component Name And Quantity:
2 semiconductor device diode
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon all semiconductor device diode
Voltage Rating In Volts Per Characteristic:
600.0 reverse voltage, peak all semiconductor device diode
Current Rating Per Characteristic:
25.00 amperes forward current, average absolute all semiconductor device diode and 400.00 amperes forward current, average preset all
semiconductor device diode
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-collector preset all semiconductor device diode
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Special Features:
Common cathode; weapon system essential; all semiconductor device diode junction pattern arrangement: pn
Test Data Document:
96214-807781 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
2 pin and 1 case
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

No

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